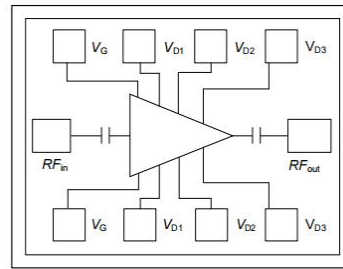


### Performance

- Frequency: 22.4~25GHz
- Typical Signal Gain: 28dB
- Typical Pout: 42dBm@24V
- Typical PAE: 37%
- Bias: 24V, -2.3V (Typ.)
- Technology: 0.15um HEMT
- Size: 2.8\*2.3mm\*0.05mm

### Function Diagram

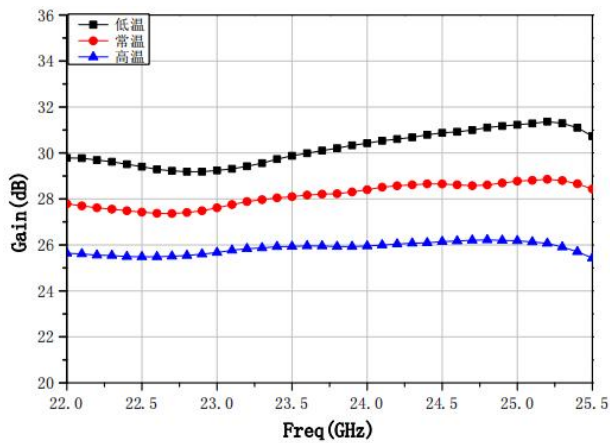


### Electrical Specifications (T<sub>A</sub>=25°C, V<sub>d</sub>=24V, I<sub>dq</sub>=0.78A, F:22.4~25GHz, CW)

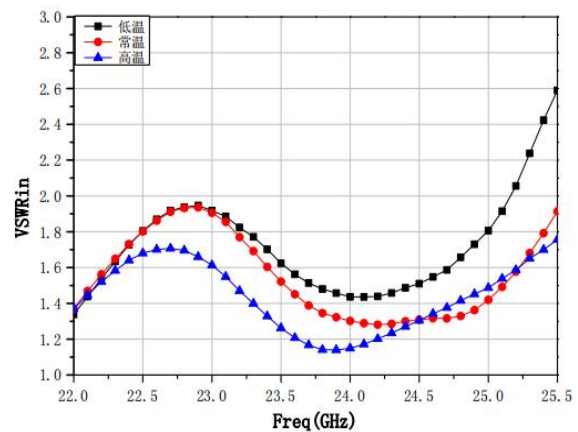
Symbol	Parameter	Min	Typical	Max	Unit
G	Small Signal Gain	-	28	-	dB
G <sub>p</sub>	Power Gain	-	22	-	dB
P <sub>out</sub>	Saturated Power	-	42	-	dBm
PAE	Power Added Efficiency	-	37	-	%

### Test Curves

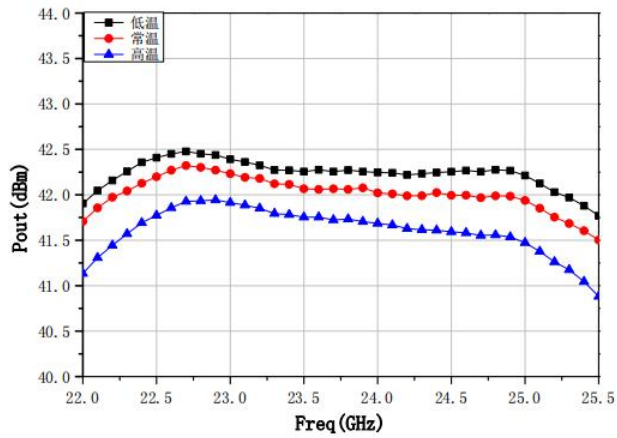
Small Signal Gain@ Different Temp



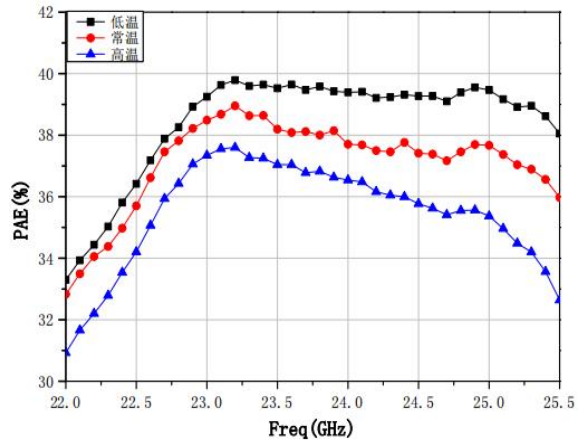
VSWRin@ Different Temp



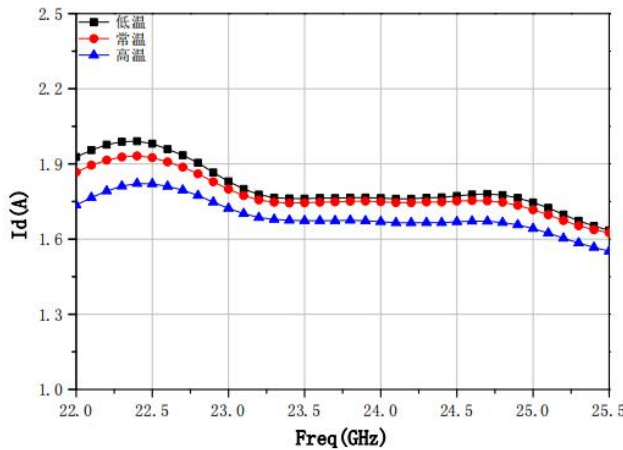
Pout@ Different Temp



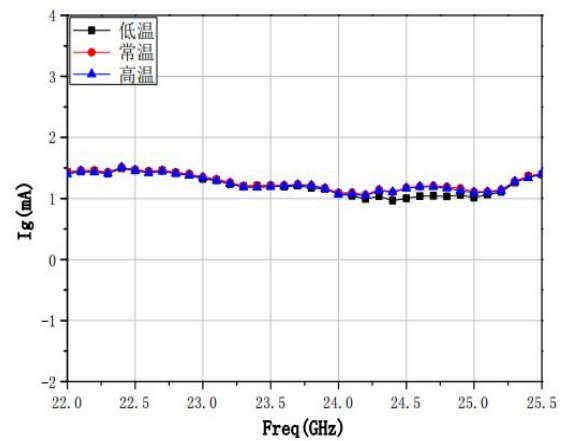
PAE@ Different Temp



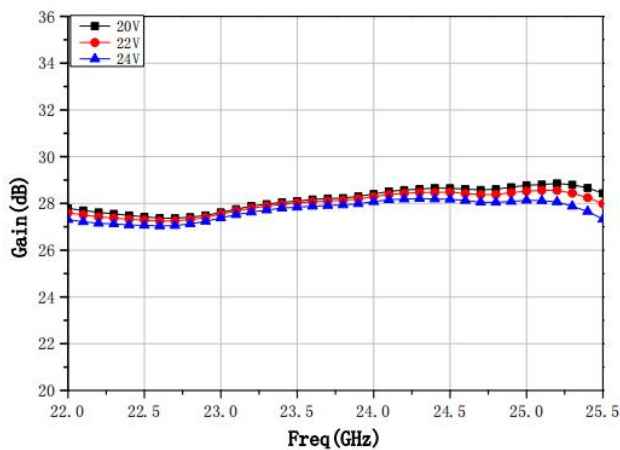
Id@ Different Temp



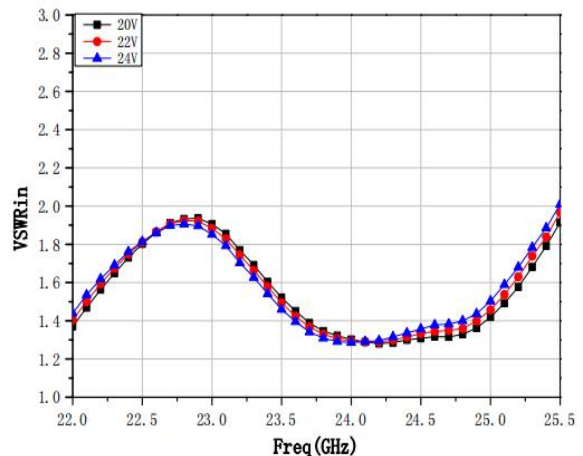
Ig@ Different Temp



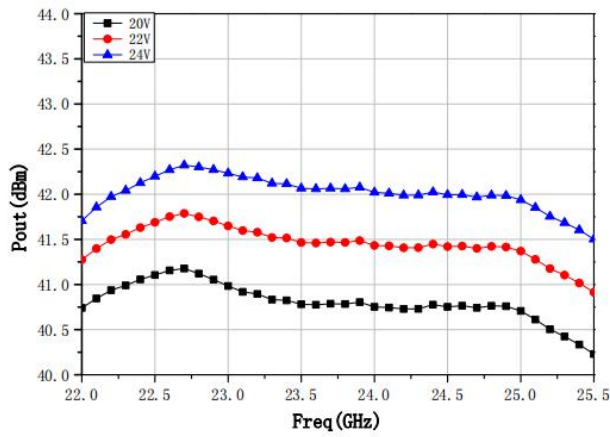
Small Signal Gain@ Different Vd



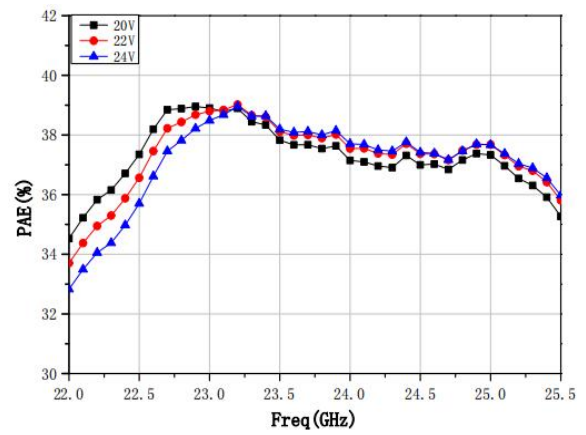
VSWRin@ Different Vd



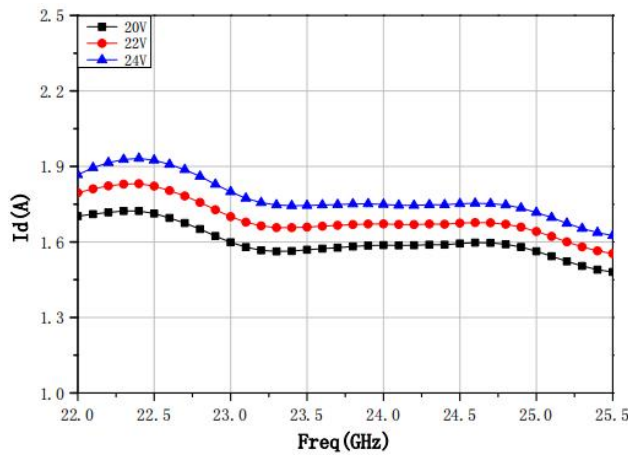
Pout@ Different Vd



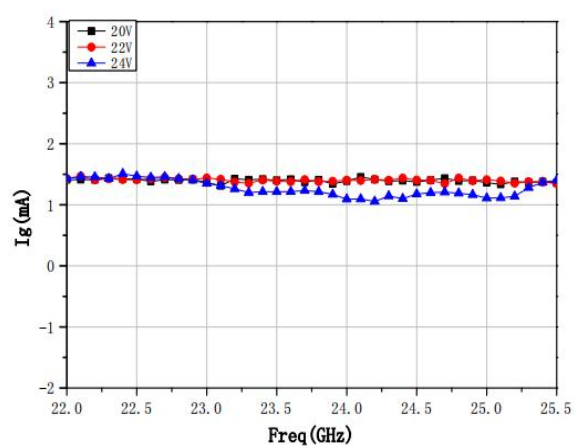
PAE@ Different Vd



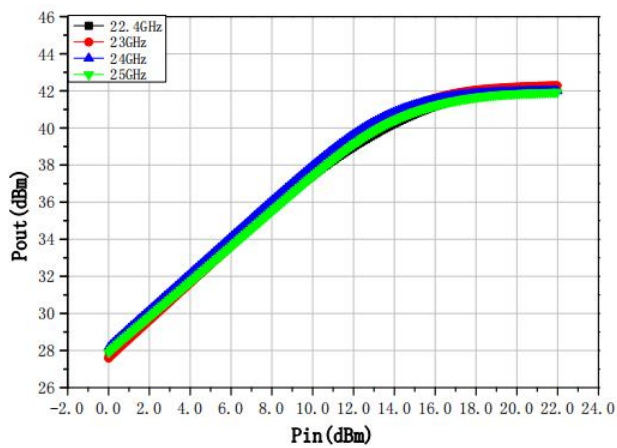
Id@ Different Vd



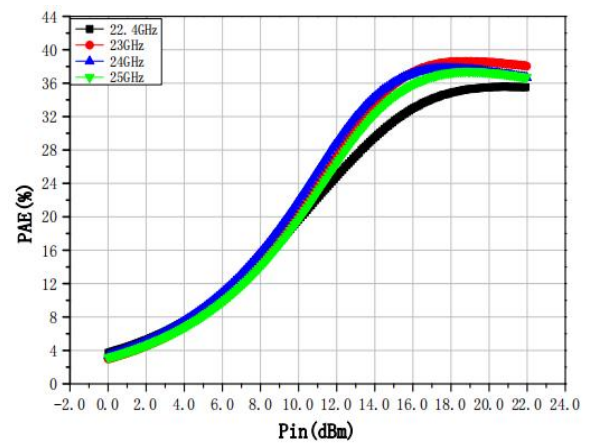
Ig@ Different Vd



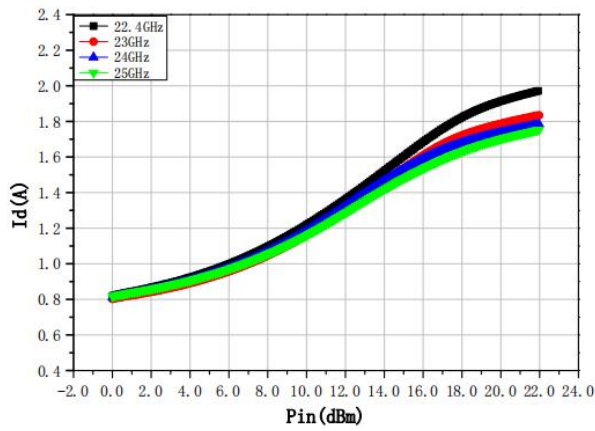
Pout@ Different Pin



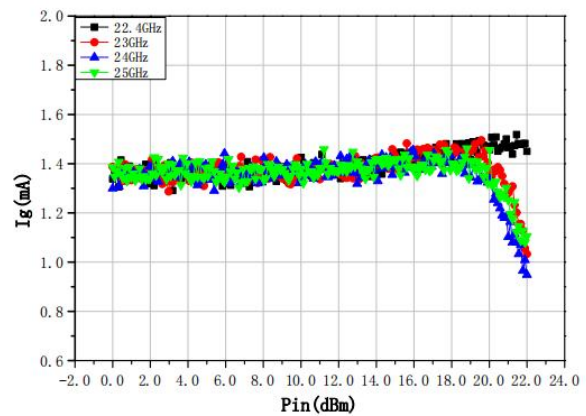
PAE@ Different Pin



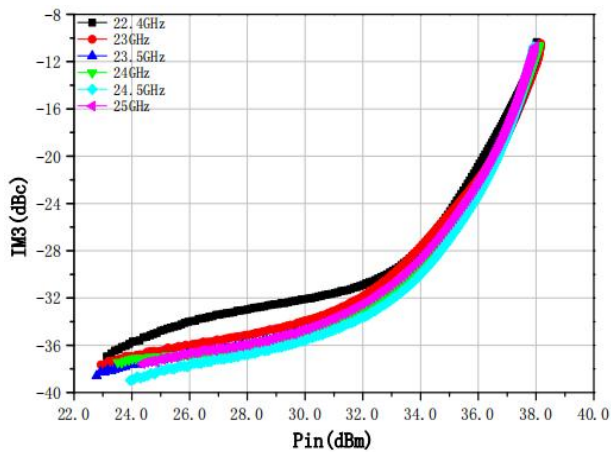
Id@ Different Pin



Ig@ Different Pin



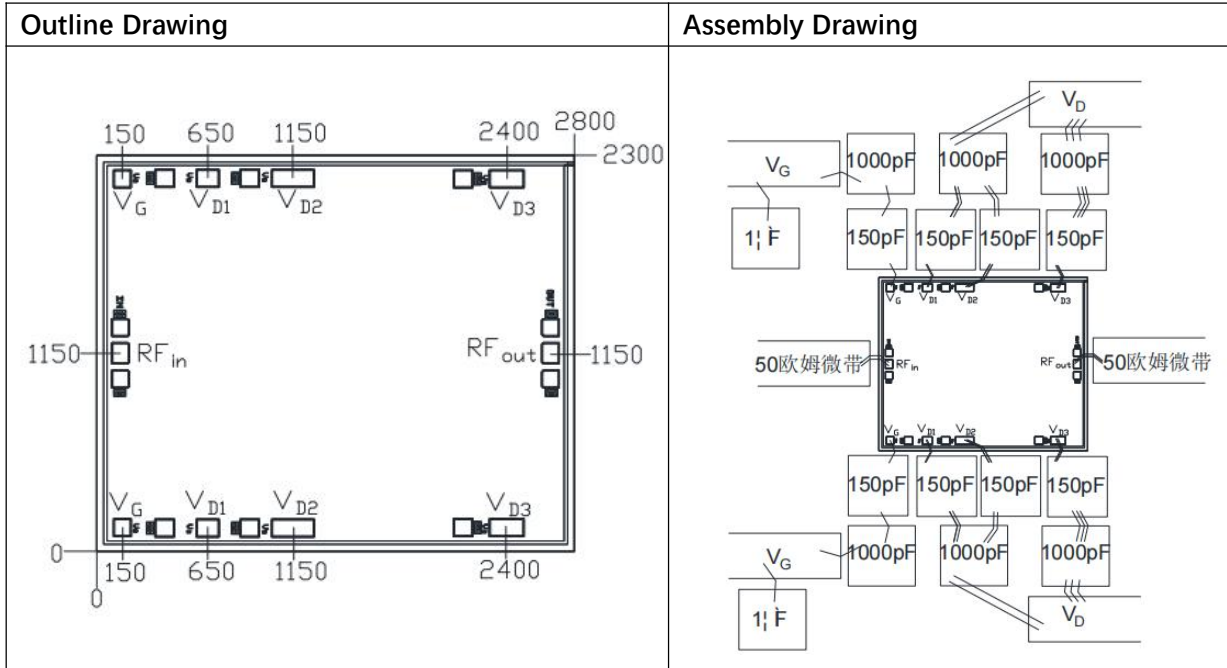
IM3@ Different Pin



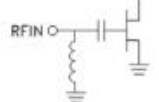

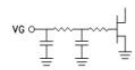

**Absolute Max Ratings (TA=25°C)**

Symbol	Parameter	Value	Remark
Vd	Drain Voltage	24V	
Id	Drain Current	2.5A	
Vg	Gate Voltage	-10V	
Ig	Gate Current	10mA	
Pd	DC Power	60W	
Pin	Input Power	25dBm	
Tch	Channel Temperature	175°C	
Tm	Mounting Temperature	310°C	1 min, N2 Protection
Tstg	Storage Temperature	-55~175°C	

Exceeding any one or combination of these limits may cause permanent damage.



### Pads Definition

Pad	Description	Equivalent Circuit
RFin	RF Signal input, connect to 50ohm system, no need block capacitor.	
RFout	RF Signal output, connect to 50ohm system, no need block capacitor.	
VG	Amp gate bias, external 150uF, 1000pF, 1uF capacitor is needed	
VD1、VD2、VD3	Amp drain bias, external 150uF, 1000pF capacitor is needed	
GND	Bottom must connect to RF and DC ground	